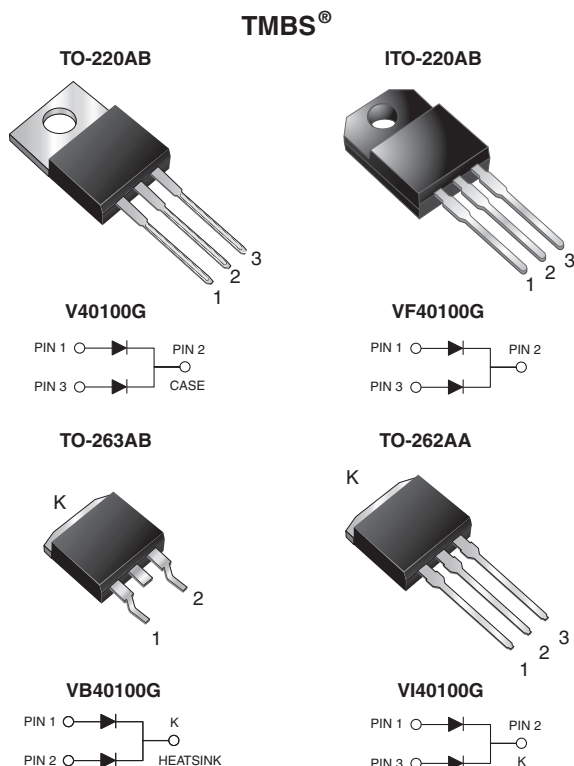


## Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.42\text{ V}$  at  $I_F = 5\text{ A}$



### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

|                              |          |
|------------------------------|----------|
| $I_{F(AV)}$                  | 2 x 20 A |
| $V_{RRM}$                    | 100 V    |
| $I_{FSM}$                    | 200 A    |
| $V_F$ at $I_F = 20\text{ A}$ | 0.67 V   |
| $T_J$ max.                   | 150 °C   |

### MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)

| PARAMETER                                                                                                | SYMBOL                            | V40100G       | VF40100G | VB40100G | VI40100G | UNIT |
|----------------------------------------------------------------------------------------------------------|-----------------------------------|---------------|----------|----------|----------|------|
| Maximum repetitive peak reverse voltage                                                                  | V <sub>RRM</sub>                  | 100           |          |          |          | V    |
| Maximum average forward rectified current <div>per device (fig. 1)</div> <div>per diode</div>            | I <sub>F(AV)</sub>                | 40            |          |          |          | A    |
|                                                                                                          |                                   | 20            |          |          |          |      |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode             | I <sub>FSM</sub>                  | 200           |          |          |          | A    |
| Non-repetitive avalanche energy at T <sub>J</sub> = 25 °C, L = 90 mH per diode                           | E <sub>AS</sub>                   | 230           |          |          |          | mJ   |
| Peak repetitive reverse current at t <sub>p</sub> = 2 μs, 1 kHz, T <sub>J</sub> = 38 °C ± 2 °C per diode | I <sub>RRM</sub>                  | 1.0           |          |          |          | A    |
| Voltage rate of change (rated V <sub>R</sub> )                                                           | dV/dt                             | 10 000        |          |          |          | V/μs |
| Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min                                   | V <sub>AC</sub>                   | 1500          |          |          |          | V    |
| Operating junction and storage temperature range                                                         | T <sub>J</sub> , T <sub>STG</sub> | - 40 to + 150 |          |          |          | °C   |

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

| PARAMETER                                              | TEST CONDITIONS                                          | SYMBOL   | TYP.     | MAX. | UNIT          |
|--------------------------------------------------------|----------------------------------------------------------|----------|----------|------|---------------|
| Breakdown voltage                                      | $I_R = 1.0\text{ mA}$ $T_A = 25\text{ }^{\circ}\text{C}$ | $V_{BR}$ | 100 min. | -    |               |
| Instantaneous forward voltage per diode <sup>(1)</sup> | $I_F = 5\text{ A}$ $T_A = 25\text{ }^{\circ}\text{C}$    | $V_F$    | 0.49     | -    | V             |
|                                                        | $I_F = 10\text{ A}$ $T_A = 25\text{ }^{\circ}\text{C}$   |          | 0.59     | -    |               |
|                                                        | $I_F = 20\text{ A}$ $T_A = 25\text{ }^{\circ}\text{C}$   |          | 0.75     | 0.81 |               |
|                                                        | $I_F = 5\text{ A}$ $T_A = 125\text{ }^{\circ}\text{C}$   |          | 0.42     | -    |               |
|                                                        | $I_F = 10\text{ A}$ $T_A = 125\text{ }^{\circ}\text{C}$  |          | 0.54     | -    |               |
|                                                        | $I_F = 20\text{ A}$ $T_A = 125\text{ }^{\circ}\text{C}$  |          | 0.67     | 0.73 |               |
| Reverse current per diode <sup>(2)</sup>               | $V_R = 70\text{ V}$ $T_A = 25\text{ }^{\circ}\text{C}$   | $I_R$    | 12       | -    | $\mu\text{A}$ |
|                                                        | $V_R = 70\text{ V}$ $T_A = 125\text{ }^{\circ}\text{C}$  |          | 8        | -    | $\text{mA}$   |
|                                                        | $V_R = 100\text{ V}$ $T_A = 25\text{ }^{\circ}\text{C}$  |          | 55       | 500  | $\mu\text{A}$ |
|                                                        | $V_R = 100\text{ V}$ $T_A = 125\text{ }^{\circ}\text{C}$ |          | 21       | 35   | $\text{mA}$   |

**Notes**(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle(2) Pulse test: Pulse width  $\leq 40\text{ ms}$ **THERMAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

| PARAMETER                            | SYMBOL          | V40100G | VF40100G | VB40100G | VI40100G | UNIT                 |
|--------------------------------------|-----------------|---------|----------|----------|----------|----------------------|
| Typical thermal resistance per diode | $R_{\theta JC}$ | 2.0     | 5.0      | 2.0      | 2.0      | $^{\circ}\text{C/W}$ |

**ORDERING INFORMATION** (Example)

| PACKAGE   | PREFERRED P/N  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
|-----------|----------------|-----------------|--------------|---------------|---------------|
| TO-220AB  | V40100G-E3/4W  | 1.88            | 4W           | 50/tube       | Tube          |
| ITO-220AB | VF40100G-E3/4W | 1.75            | 4W           | 50/tube       | Tube          |
| TO-263AB  | VB40100G-E3/4W | 1.39            | 4W           | 50/tube       | Tube          |
| TO-263AB  | VB40100G-E3/8W | 1.39            | 8W           | 800/reel      | Tape and reel |
| TO-262AA  | VI40100G-E3/4W | 1.46            | 4W           | 50/tube       | Tube          |

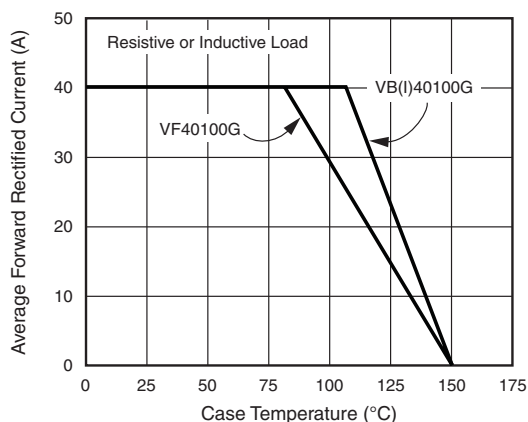
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

Fig. 1 - Maximum Forward Current Derating Curve

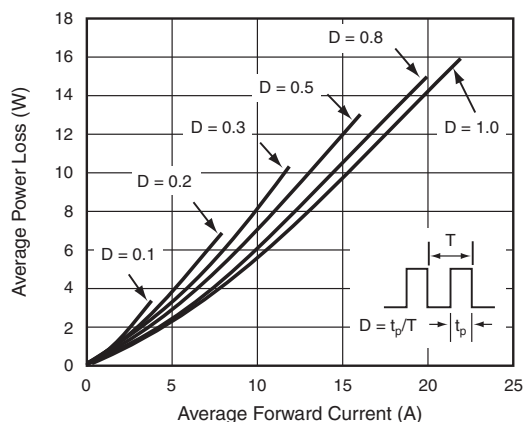


Fig. 2 - Forward Power Loss Characteristics

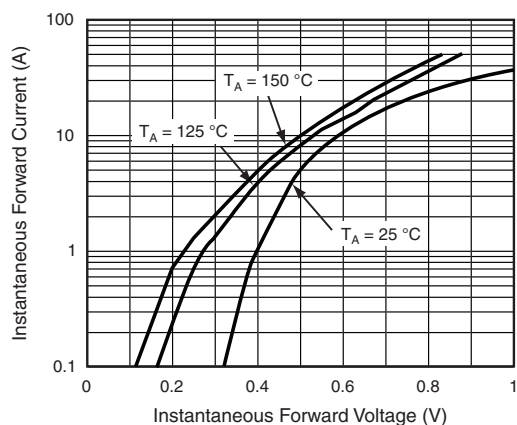


Fig. 3 - Typical Instantaneous Forward Characteristics

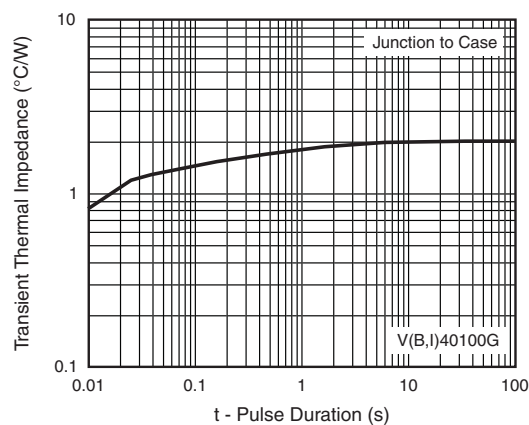


Fig. 6 - Typical Transient Thermal Impedance

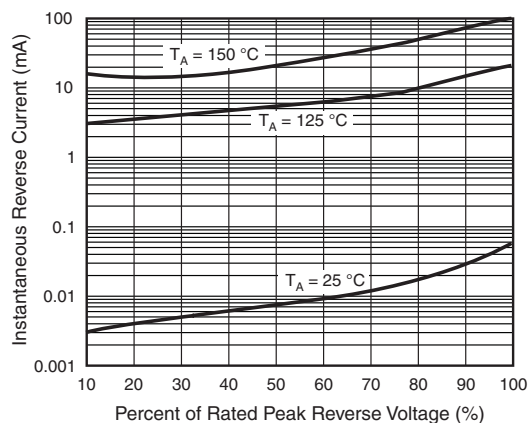


Fig. 4 - Typical Reverse Characteristics

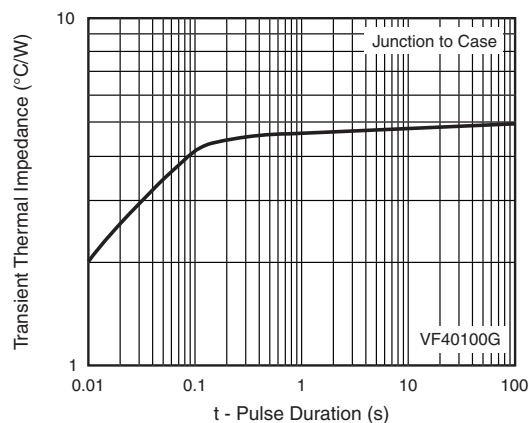


Fig. 7 - Typical Transient Thermal Impedance

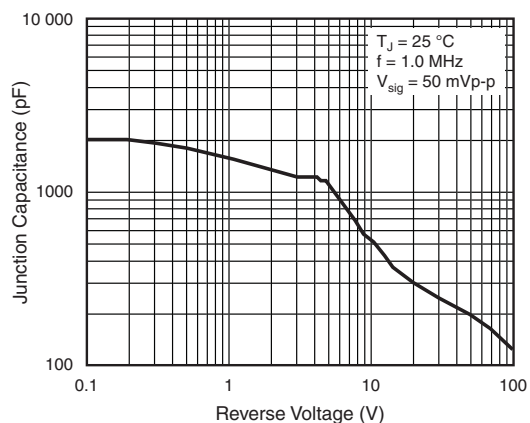
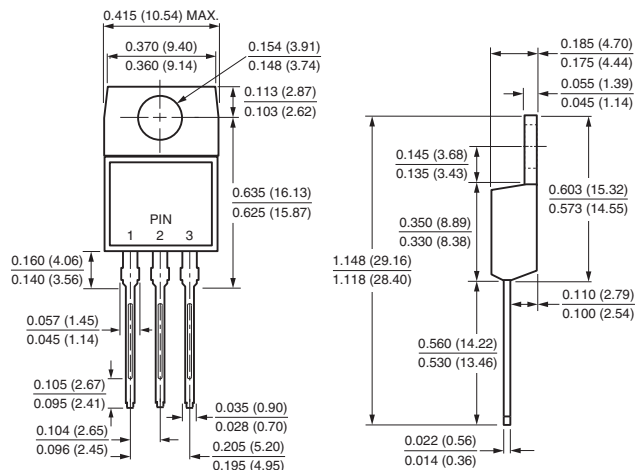


Fig. 5 - Typical Junction Capacitance

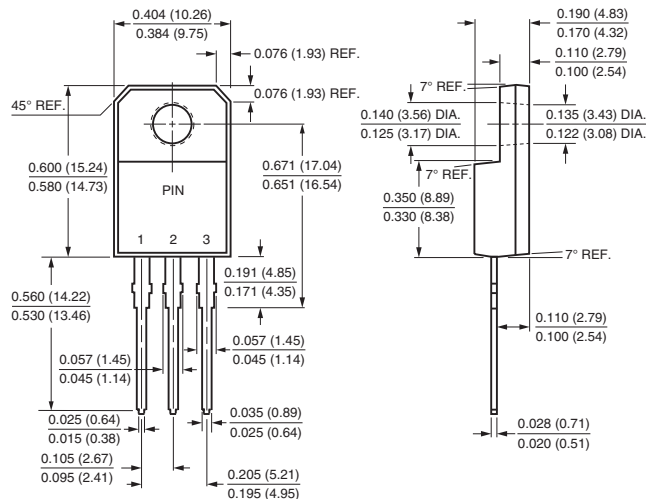


## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

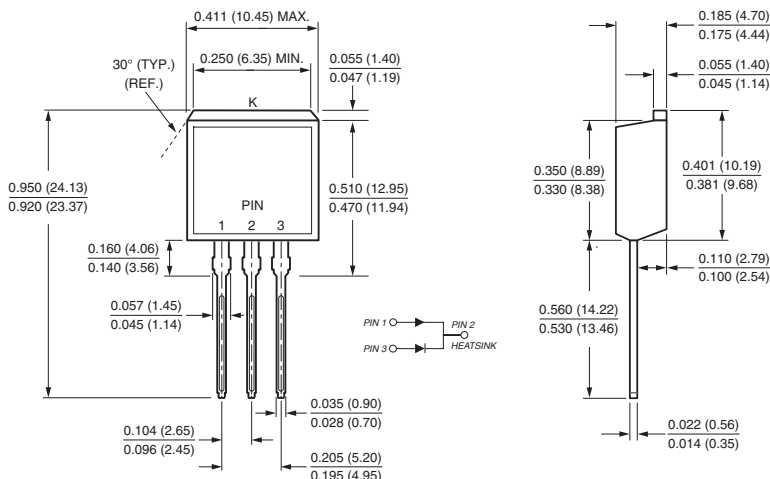
TO-220AB



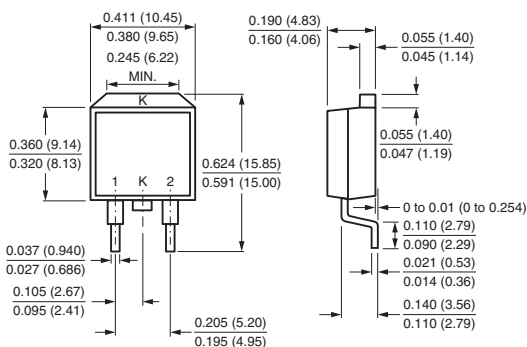
ITO-220AB



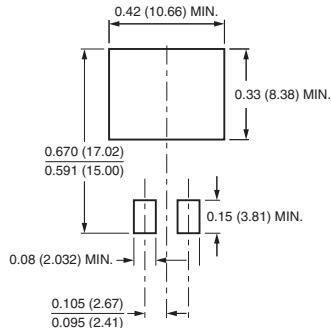
TO-262AA



TO-263AB



Mounting Pad Layout





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